LDO Linear Regulators - Micropower, DELAY, Adjustable RESET, General Use Comparator

400 mA

The NCV8504 is a family of precision micropower voltage regulators. Their output current capability is 400 mA. The family has output voltage options for Adjustable, 2.5 V, 3.3 V and 5.0 V.

The output voltage is accurate within $\pm 2.0\%$ with a maximum dropout voltage of 0.6 V at 400 mA. Low quiescent current is a feature drawing only 100 μ A with a 100 μ A load. This part is ideal for any and all battery operated microprocessor equipment.

Microprocessor control logic includes an active $\overline{\text{RESET}}$ (with DELAY).

The active \overline{RESET} circuit operates correctly at an output voltage as low as 1.0 V. The \overline{RESET} function is activated during the power up sequence or during normal operation if the output voltage drops below the regulation limits.

The reset threshold voltage can be decreased by the connection of external resistor divider to R_{ADJ} lead.

The general use comparator ($\overline{FLAG}/Monitor$) is referenced to a temperature stable voltage and provides 1 mA of drive current at its open collector output.

The regulator is protected against reverse battery, short circuit, and thermal overload conditions. The device can withstand load dump transients making it suitable for use in automotive environments. The device has also been optimized for EMC conditions.

Features

- Output Voltage Options: Adjustable, 2.5 V, 3.3 V, 5.0 V
- ± 2.0% Output
- Low 100 μA Quiescent Current
- Fixed or Adjustable Output Voltage
- Active RESET
- Adjustable Reset
- 400 mA Output Current Capability
- Fault Protection
 - ♦ +60 V Peak Transient Voltage
 - → -15 V Reverse Voltage
 - Short Circuit
 - ◆ Thermal Overload
- General Use Comparator
- NCV Prefix for Automotive and Other Applications Requiring Site and Change Control
- AEC Qualified
- PPAP Capable
- These are Pb-Free Devices



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SOIC 16 LEAD WIDE BODY EXPOSED PAD PDW SUFFIX CASE 751AG



MARKING

x = Voltage Ratings as Indicated Below:

A = Adjustable

2 = 2.5 V

3 = 3.3 V

5 = 5.0 V = Assembly Location

WL = Wafer Lot

YY = Year

WW = Work Week

G = Pb-Free Device

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

PIN CONNECTIONS



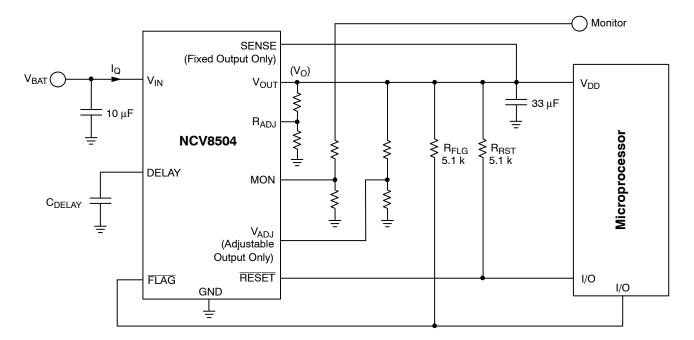


Figure 1. Application Diagram

MAXIMUM RATINGS*†

Rating		Value	Unit
V _{IN} (DC)		-15 to 45	V
Peak Transient Voltage (46 V Load Dump @ V _{IN} = 14 V)		60	V
Operating Voltage		45	V
V _{OUT} (DC)		-0.3 to 16	V
Voltage Range (RESET, FLAG, R _{ADJ} , DELAY)		-0.3 to 10	V
Input Voltage Range MON V _{ADJ}		-0.3 to 10 -0.3 to 16	V V
ESD Susceptibility (Human Body Model) (Machine Model)		4.0 200	kV V
Junction Temperature, T _J		-40 to +150	°C
Storage Temperature, T _S		–55 to 150	°C
Package Thermal Resistance, SOW-16 E PAD: Junction-to-Case, R _{θJC} Junction-to-Ambient, R _{θJA}		16 57	°C/W °C/W
Lead Temperature Soldering:	260 peak (Note 2)	°C	

 ^{1. 150} second maximum above 217°C.
 2. -5°C/+0°C allowable conditions.

$\textbf{ELECTRICAL CHARACTERISTICS} \text{ ($I_{OUT} = 1.0$ mA, -40°C} \leq T_{J} \leq 150^{\circ}$C; $V_{IN} = \text{dependent on voltage option (Note 3);} \\$ unless otherwise specified.)

Characteristic	Test Conditions	Min	Тур	Max	Unit
Output Stage					
Output Voltage for 2.5 V Option (V _O)	$6.5 \text{ V} < V_{\text{IN}} < 16 \text{ V}, 1.0 \text{ mA} \le I_{\text{OUT}} \le 400 \text{ mA}$ 4.5 V $<$ V _{IN} $<$ 26 V , 1.0 mA \le I _{OUT} \le 400 mA	2.450 2.425	2.5 2.5	2.550 2.575	V V
Output Voltage for 3.3 V Option (V _O)	7.3 V < V_{IN} < 16 V, 1.0 mA \leq I_{OUT} \leq 400 mA 4.5 V < V_{IN} < 26 V, 1.0 mA \leq I_{OUT} \leq 400 mA	3.234 3.201	3.3 3.3	3.366 3.399	V V
Output Voltage for 5.0 V Option (V _O)	9.0 V < V_{IN} < 16 V, 1.0 mA \leq I_{OUT} \leq 400 mA 6.0 V < V_{IN} < 26 V, 1.0 mA \leq I_{OUT} \leq 400 mA	4.90 4.85	5.0 5.0	5.10 5.15	V
Output Voltage for Adjustable Option (V _O)	V _{OUT} = V _{ADJ} (Unity Gain) 6.5 V < V _{IN} < 16 V, 1.0 mA < I _{OUT} < 400 mA 4.5 V < V _{IN} < 26 V , 1.0 mA < I _{OUT} < 400 mA	1.274 1.261	1.300 1.306	1.326 1.339	V V
Dropout Voltage (V _{IN} – V _{OUT}) (5.0 V and Adj. > 5.0 V Options Only)	I _{OUT} = 400 mA I _{OUT} = 1.0 mA	-	400 30	600 150	mV mV
Load Regulation	V _{IN} = 14 V, 5.0 mA ≤ I _{OUT} ≤ 400 mA	-30	5.0	30	mV
Line Regulation (2.5 V, 3.3 V, and Adjustable Options)	4.5 V < V _{IN} < 26 V, I _{OUT} = 1.0 mA	-	5.0	25	mV
Line Regulation (5.0 V Option)	6.0 V < V _{IN} < 26 V, I _{OUT} = 1.0 mA	_	5.0	25	mV
Quiescent Current, (I _Q) Active Mode	$\begin{split} I_{OUT} &= 100~\mu\text{A},~V_{IN} = 12~\text{V},~\text{Delay} = 3.0~\text{V},~\text{MON} = 3.0~\text{V}\\ I_{OUT} &= 75~\text{mA},~V_{IN} = 14~\text{V},~\text{Delay} = 3.0~\text{V},~\text{MON} = 3.0~\text{V}\\ I_{OUT} &\leq 400~\text{mA},~V_{IN} = 14~\text{V},~\text{Delay} = 3.0~\text{V},~\text{MON} = 3.0~\text{V} \end{split}$	- - -	100 2.5 25	150 5.0 45	μA mA mA
Current Limit	-	425	800	-	mA
Short Circuit Output Current	V _{OUT} = 0 V	100	500	_	mA
Thermal Shutdown	(Guaranteed by Design)	150	180	-	°C

^{3.} Voltage range specified in the Output Stage of the Electrical Characteristics in boldface type.

^{*}The maximum package power dissipation must be observed.

[†]During the voltage range which exceeds the maximum tested voltage of V_{IN}, operation is assured, but not specified. Wider limits may apply. Thermal dissipation must be observed closely.

 $\textbf{ELECTRICAL CHARACTERISTICS (continued)} \ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = \text{dependent on voltage option (Note 4)}; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = \text{dependent on voltage option (Note 4)}; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = \text{dependent on voltage option (Note 4)}; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = \text{dependent on voltage option (Note 4)}; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = \text{dependent on voltage option (Note 4)}; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = \text{dependent on voltage option (Note 4)}; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = \text{dependent on voltage option (Note 4)}; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = \text{dependent on voltage option (Note 4)}; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = \text{dependent on voltage option (Note 4)}; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = \text{dependent on voltage option (Note 4)}; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = \text{dependent on voltage option (Note 4)}; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = \text{dependent on voltage option (Note 4)}; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = \text{dependent on voltage option (Note 4)}; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = 100 ^{\circ}C; \ \, V_{IN} = 100 ^{\circ}C; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq T_{J} \leq 150 ^{\circ}C; \ \, V_{IN} = 100 ^{\circ}C; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq 150 ^{\circ}C; \ \, V_{IN} = 100 ^{\circ}C; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq 150 ^{\circ}C; \ \, V_{IN} = 100 ^{\circ}C; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq 150 ^{\circ}C; \ \, V_{IN} = 100 ^{\circ}C; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq 150 ^{\circ}C; \ \, V_{IN} = 100 ^{\circ}C; \\ \, (I_{OUT} = 1.0 \ mA, \ -40 ^{\circ}C \leq 15$ unless otherwise specified.)

Characteristic	Test Conditions	Min	Тур	Max	Unit
Reset Function (RESET)					•
RESET Threshold for 2.5 V Option HIGH (V _{RH}) LOW (V _{RL}) Hysteresis	V _{IN} = 4.5 V (Note 5) (Note 6) V _{OUT} Increasing V _{OUT} Decreasing	2.35 2.30 25	- - -	1.0 × V _O	V V mV
RESET Threshold for 3.3 V Option HIGH (V _{RH}) LOW (V _{RL}) Hysteresis	V _{IN} = 4.5 V (Note 5) (Note 6) V _{OUT} Increasing V _{OUT} Decreasing	3.10 3.00 35	- - -	1.0 × V _O	V V mV
RESET Threshold for 5.0 V Option HIGH (V _{RH}) LOW (V _{RL}) Hysteresis	V _{IN} = 6.0 V (Note 6) V _{OUT} Increasing V _{OUT} Decreasing	4.70 4.60 50	- - -	1.0 × V _O	V V mV
RESET Threshold for Adjustable Option HIGH (V _{RH}) LOW (V _{RL}) Hysteresis	V _{IN} = 4.5 V (Note 5) (Note 6) V _{OUT} Increasing V _{OUT} Decreasing	1.22 1.19 10	- - -	1.0 × V _O	V V mV
RESET Output Voltage Low (V _{RLO})	V_{IN} = Minimum (Note 6) (Note 7) 1.0 V \leq V _{OUT} \leq V _{RL} , R _{RESET} = 5.1 k	-	0.1	0.4	V
DELAY Switching Threshold (V _{DT}) (2.5 V, 3.3 V, and 5.0 V Options)	V _{IN} = Minimum (Note 6) (Note 7)	1.4	1.8	2.2	V
DELAY Switching Threshold (V _{DT}) (Adjustable Option)	V _{IN} = Minimum (Note 6) (Note 7)	1.0	1.3	1.6	V
DELAY Low Voltage	V _{IN} = Minimum (Note 6) (Note 7) V _{OUT} < RESET Threshold Low(min)	-	-	0.2	V
DELAY Charge Current	V _{IN} = Minimum (Note 6) (Note 7) DELAY = 1.0 V, V _{OUT} > V _{RH}	2.5	4.0	5.5	μА
DELAY Discharge Current	V _{IN} = Minimum (Note 6) (Note 7) DELAY = 1.0 V, V _{OUT} < V _{RL}	5.0	-	-	mA
Reset Adjust Switching Voltage (V _{R(ADJ)}) Hysteresis	V _{IN} = Minimum (Note 6) (Note 7) Increasing and Decreasing	1.16 20	1.25 50	1.34 100	V mV
FLAG/Monitor					•
Monitor Threshold	Increasing and Decreasing, V _{IN} = Minimum (Note 6) (Note 7)	1.22	1.29	1.36	V
Hysteresis	V _{IN} = Minimum (Note 6) (Note 7)	10	35	75	mV
Input Current	MON = 2.0 V	-1.0	0.1	1.0	μА
Output Saturation Voltage	MON = 0 V, I _{FLAG} = 1.0 mA, V _{IN} = Minimum (Note 6) (Note 7)	-	0.1	0.4	V
Voltage Adjust (Adjustable Output only)		•	•	•	•
Input Current	V _{ADJ} = 1.25 V	-0.5	_	0.5	μА

^{4.} Voltage range specified in the Output Stage of the Electrical Characteristics in boldface type.
5. For V_{IN} ≤ 4.5 V, a RESET = Low may occur with the output in regulation.
6. Part is guaranteed by design to meet specification over the entire V_{IN} voltage range, but is production tested only at the specified V_{IN}

^{7.} Minimum V_{IN} = 4.5 V for 2.5 V, 3.3 V, and Adjustable options. Minimum V_{IN} = 6.0 V for 5.0 V option.

PACKAGE PIN DESCRIPTION, ADJUSTABLE OUTPUT

Pin Number	Pin Symbol	Function	
1	V _{ADJ}	Voltage Adjust. A resistor divider from V _{OUT} to this lead sets the output voltage.	
2	V _{OUT}	±2.0%, 400 mA output.	
3–6, 11, 12, 14	NC	No connection.	
7	V _{IN}	Input Voltage.	
8	MON	Monitor. Input to comparator. If not needed connect to V _{OUT} .	
9	R _{ADJ}	Reset Adjust. If not needed connect to ground.	
10	DELAY	Timing capacitor for RESET function.	
13	GND	Ground. All GND leads must be connected to Ground	
15	RESET	Active reset (accurate to V _{OUT} ≥ 1.0 V)	
16	FLAG	Open collector output from comparator.	

NOTE: Tentative pinout for SOW-16 E Pad.

PACKAGE PIN DESCRIPTION, FIXED OUTPUT

Pin Number	Pin Symbol	Function
1	SENSE	Kelvin connection which allows remote sensing of output voltage for improved regulation. If remote sensing is not desired, connect to V_{OUT} .
2	V _{OUT}	±2.0%, 400 mA output.
3–6, 11, 12, 14	NC	No connection.
7	V_{IN}	Input Voltage.
8	MON	Monitor. Input to comparator. If not needed connect to V _{OUT} .
9	R_{ADJ}	Reset Adjust. If not needed connect to ground.
10	DELAY	Timing capacitor for RESET function.
13	GND	Ground. All GND leads must be connected to Ground
15	RESET	Active reset (accurate to V _{OUT} ≥ 1.0 V)
16	FLAG	Open collector output from comparator.

NOTE: Tentative pinout for SOW-16 E Pad.

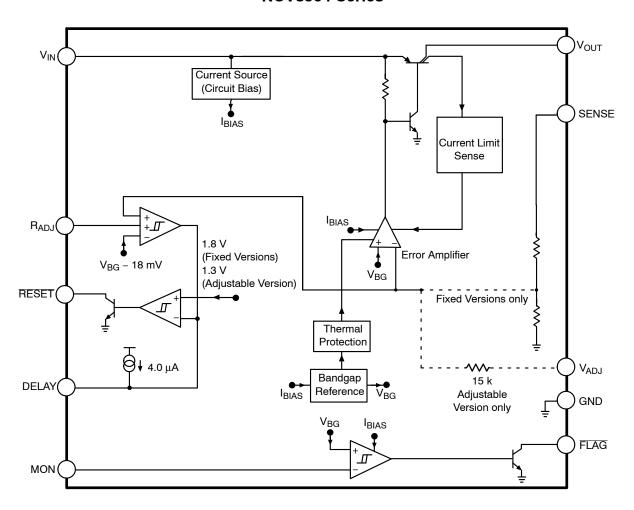


Figure 2. Block Diagram

TYPICAL PERFORMANCE CHARACTERISTICS

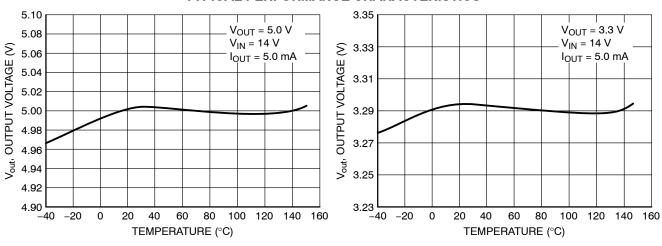


Figure 3. 5 V Output Voltage vs Temperature

Figure 4. 3.3 V Output Voltage vs Temperature

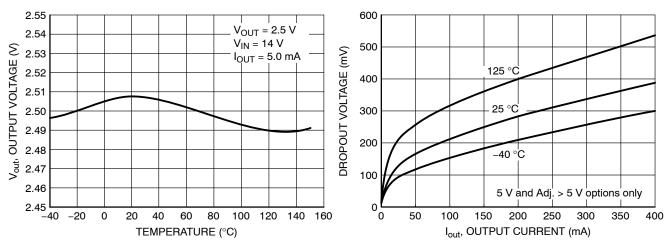


Figure 5. 2.5 V Output Voltage vs Temperature

Figure 6. Dropout Voltage vs Output Current

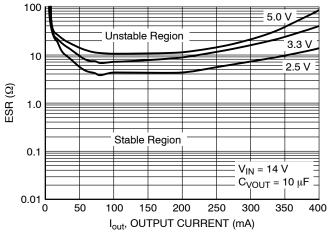


Figure 7. Output Stability with Output Voltage Change

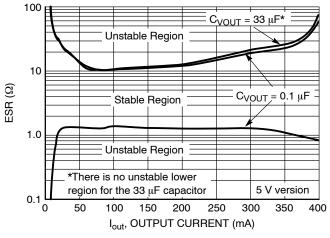
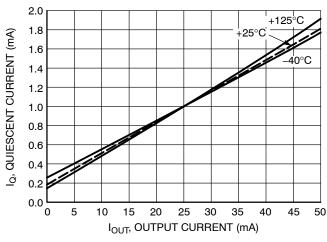


Figure 8. Output Stability with Output Capacitor Change

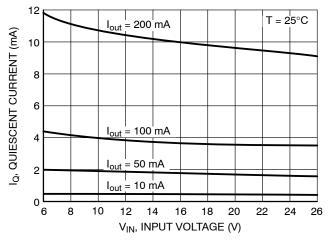
TYPICAL PERFORMANCE CHARACTERISTICS



60 (VE) 50 10 0 50 100 150 200 250 300 350 400 450 500 HOUT, OUTPUT CURRENT (mA)

Figure 9. Quiescent Current vs Output Current

Figure 10. Quiescent Current vs Output Current



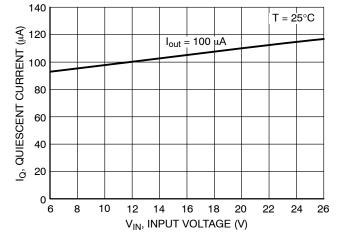


Figure 11. Quiescent Current vs Input Voltage

Figure 12. Quiescent Current vs Input Voltage

CIRCUIT DESCRIPTION

REGULATOR CONTROL FUNCTIONS

The NCV8504 contains the microprocessor compatible control function \overline{RESET} (Figure 13).

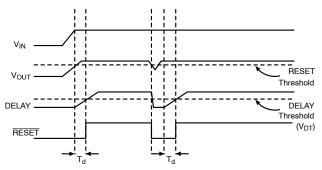


Figure 13. Reset and Delay Circuit Wave Forms

RESET Function

A \overline{RESET} signal (low voltage) is generated as the IC powers up until V_{OUT} is within 1.5% of the regulated output voltage, or when V_{OUT} drops out of regulation,and is lower than 4.0% below the regulated output voltage. Hysteresis is included in the function to minimize oscillations.

The \overline{RESET} output is an open collector NPN transistor, controlled by a low voltage detection circuit. The circuit is functionally independent of the rest of the IC thereby guaranteeing that the \overline{RESET} signal is valid for V_{OUT} as low as 1.0 V.

Adjustable Reset Function

The reset threshold can be made lower by connecting an external resistor divider to the R_{ADJ} lead from the V_{OUT} lead, as displayed in Figure 14. This lead is grounded to select the default value of 4.6 V (on the 5.0 V option).

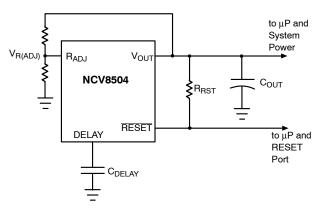


Figure 14. Adjustable RESET

DELAY Function

The reset delay circuit provides a programmable (by external capacitor) delay on the \overline{RESET} output lead.

The DELAY lead provides source current (typically $4.0~\mu A$) to the external DELAY capacitor during the following proceedings:

- 1. During Power Up (once the regulation threshold has been verified).
- 2. After a reset event has occurred and the device is back in regulation. The DELAY capacitor is discharged when the regulation (RESET threshold) has been violated. This is a latched incident. The capacitor will fully discharge and wait for the device to regulate before going through the delay time event again.

FLAG/Monitor Comparator

A general use comparator is included whose positive input terminal is tied to the on-chip bandgap voltage reference. This provides a very temperature stable referenced comparator with versatile use in any system. The trip point can be programmed externally using a resistor divider to the input monitor (MON) (Figure 15). The typical threshold is 1.29 V on the MON pin.

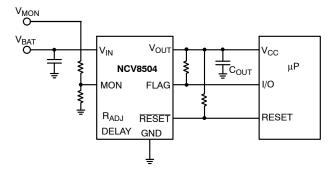


Figure 15. Flag/Monitor Function

Voltage Adjust

Figure 16 shows the device setup for a user configurable output voltage. The feedback to the V_{ADJ} pin is taken from a voltage divider referenced to the output voltage. The loop is balanced around the Unity Gain threshold (1.30 V typical).

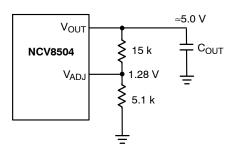


Figure 16. Adjustable Output Voltage

APPLICATION NOTES

FLAG MONITOR

Figure 17 shows the FLAG Monitor waveforms as a result of the circuit depicted in Figure 15. As the input voltage falls (V_{MON}), the Monitor threshold is crossed. This causes the voltage on the \overline{FLAG} output to go low.

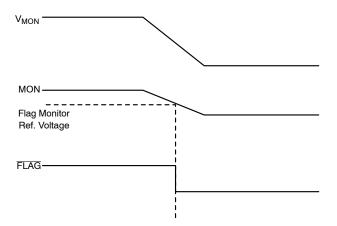


Figure 17. FLAG Monitor Circuit Waveform

SETTING THE DELAY TIME

The delay time is controlled by the Reset Delay Low Voltage, Delay Switching Threshold, and the Delay Charge Current. The delay follows the equation:

$$t_{DELAY} = \frac{\left[C_{DELAY}(V_{dt} - \text{Reset Delay Low Voltage})\right]}{\text{Delay Charge Current}}$$

Example:

Using $C_{DELAY} = 33 \text{ nF}$.

Assume reset Delay Low Voltage = 0.

Use the typical value for $V_{dt} = 1.8 \text{ V}$ (2.5 V, 3.3 V, and 5.0 V options).

Use the typical value for Delay Charge Current = $4.2 \mu A$.

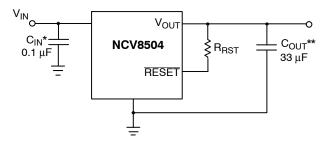
$$t_{DELAY} = \frac{[33 \text{ nF}(1.8 - 0)]}{4.2 \,\mu\text{A}} = 14 \text{ ms}$$

STABILITY CONSIDERATIONS

The output or compensation capacitor helps determine three main characteristics of a linear regulator: start-up delay, load transient response and loop stability.

The capacitor value and type should be based on cost, availability, size and temperature constraints. A tantalum or aluminum electrolytic capacitor is best, since a film or ceramic capacitor with almost zero ESR can cause instability. The aluminum electrolytic capacitor is the least expensive solution, but, if the circuit operates at low temperatures (-25°C to -40°C), both the value and ESR of the capacitor will vary considerably. The capacitor manufacturers data sheet usually provides this information.

The value for the output capacitor C_{OUT} shown in Figure 18 should work for most applications, however it is not necessarily the optimized solution.



*C_{IN} required if regulator is located far from the power supply filter

**C_{OUT} required for stability. Capacitor must operate at minimum
temperature expected

Figure 18. Test and Application Circuit Showing Output Compensation

CALCULATING POWER DISSIPATION IN A SINGLE OUTPUT LINEAR REGULATOR

The maximum power dissipation for a single output regulator (Figure 19) is:

$$PD(max) = [VIN(max) - VOUT(min)]IOUT(max) + VIN(max)IQ$$
 (1)

where:

 $V_{IN(max)}$ is the maximum input voltage,

V_{OUT(min)} is the minimum output voltage,

 $I_{OUT(max)}$ is the maximum output current for the application, and

 I_Q is the quiescent current the regulator consumes at $I_{OUT(max)}$.

Once the value of $P_{D(max)}$ is known, the maximum permissible value of $R_{\theta JA}$ can be calculated:

$$R_{\theta JA} = \frac{150^{\circ}C - T_{A}}{P_{D}}$$
 (2)

The value of $R_{\theta JA}$ can then be compared with those in the package section of the data sheet. Those packages with $R_{\theta JA}$'s less than the calculated value in equation 2 will keep the die temperature below 150°C.

In some cases, none of the packages will be sufficient to dissipate the heat generated by the IC, and an external heatsink will be required.

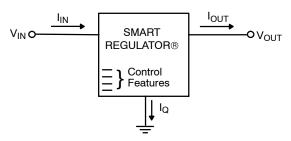


Figure 19. Single Output Regulator with Key Performance Parameters Labeled

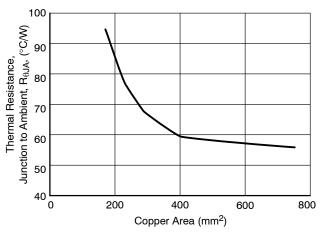


Figure 20. 16 Lead SOW (Exposed Pad), θJA as a Function of the Pad Copper Area (2 oz. Cu Thickness), Board Material = 0.0625" G-10/R-4

HEAT SINKS

A heat sink effectively increases the surface area of the package to improve the flow of heat away from the IC and into the surrounding air.

Each material in the heat flow path between the IC and the outside environment will have a thermal resistance. Like series electrical resistances, these resistances are summed to determine the value of $R_{\theta IA}$:

$$R_{\theta}JA = R_{\theta}JC + R_{\theta}CS + R_{\theta}SA \tag{3}$$

where:

 $R_{\theta JC}$ = the junction-to-case thermal resistance,

 $R_{\theta CS}$ = the case-to-heatsink thermal resistance, and

 $R_{\theta SA}$ = the heatsink-to-ambient thermal resistance.

 $R_{\theta JC}$ appears in the package section of the data sheet. Like $R_{\theta JA}$, it too is a function of package type. $R_{\theta CS}$ and $R_{\theta SA}$ are functions of the package type, heatsink and the interface between them. These values appear in heat sink data sheets of heat sink manufacturers.

ORDERING INFORMATION

Device	Output Voltage	Package	Shipping [†]
NCV8504PWADJG	A.E	SOW-16 Exposed Pad (Pb-Free)	47 Units/Rail
NCV8504PWADJR2G	- Adjustable -	SOW-16 Exposed Pad (Pb-Free)	1000 Tape & Reel
NCV8504PW25G	0.51/	SOW-16 Exposed Pad (Pb-Free)	47 Units/Rail
NCV8504PW25R2G	2.5 V	SOW-16 Exposed Pad (Pb-Free)	1000 Tape & Reel
NCV8504PW33G	221	SOW-16 Exposed Pad (Pb-Free)	47 Units/Rail
NCV8504PW33R2G	3.3 V	SOW-16 Exposed Pad (Pb-Free)	1000 Tape & Reel
NCV8504PW50G	5.0 V	SOW-16 Exposed Pad (Pb-Free)	47 Units/Rail
NCV8504PW50R2G		SOW-16 Exposed Pad (Pb-Free)	1000 Tape & Reel

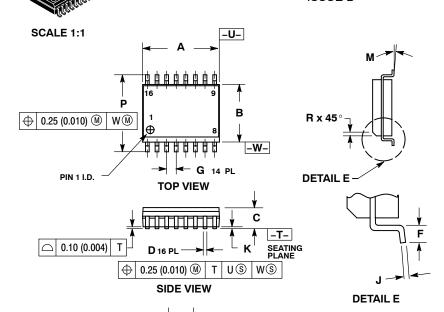
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

EXPOSED PAD

SOIC 16 LEAD WIDE BODY, EXPOSED PAD

CASE 751AG ISSUE B

DATE 31 MAY 2016

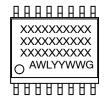


NOTES: 1. DIN

- . DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982.
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 (0.06) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 6. 751R-01 OBSOLETE, NEW STANDARD 751R-02.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	10.15	10.45	0.400	0.411	
В	7.40	7.60	0.292	0.299	
С	2.35	2.65	0.093	0.104	
D	0.35	0.49	0.014	0.019	
F	0.50	0.90	0.020	0.035	
G	1.27 BSC		0.050 BSC		
Н	3.45	3.66	0.136	0.144	
J	0.25	0.32	0.010	0.012	
K	0.00	0.10	0.000	0.004	
L	4.72	4.93	0.186	0.194	
M	0 °	7 °	0 °	7 °	
P	10.05	10.55	0.395	0.415	
R	0.25	0.75	0.010	0.029	

GENERIC MARKING DIAGRAM*



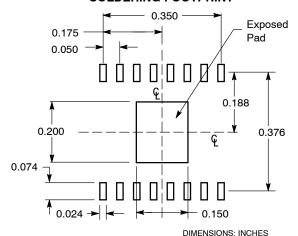
XXXXX = Specific Device Code

A = Assembly Location

WL = Wafer Lot
 YY = Year
 WW = Work Week
 G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot " ■", may or may not be present.

BOTTOM VIEW SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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